



11 Publication number:

0 563 973 A2

(2)

EUROPEAN PATENT APPLICATION

(1) Application number: 93105451.4

(51) Int. Ci.5: H01L 27/118

② Date of filing: 01.04.93

Priority: 01.04.92 JP 79708/92

Date of publication of application:
 06.10.93 Bulletin 93/40

Designated Contracting States:
DE FR GB

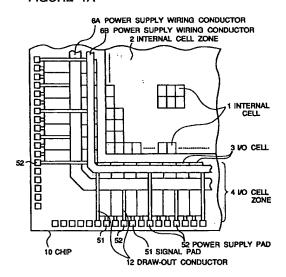
71 Applicant: NEC CORPORATION
7-1, Shiba 5-chome
Minato-ku
Tokyo 108-01(JP)

Inventor: Iruka, Masao, c/o NEC Corporation 7-1, Shiba 5-chome, Minato-ku Tokyo(JP)

Representative: Glawe, Delfs, Moll & Partner Patentanwälte Postfach 26 01 62 D-80058 München (DE)

- Master slice Integrated circuit having a reduced chip size and a reduced power supply noise.
- n a master slice integrated circuit, a number of connection pads are located in a peripheral edge region of a chip in such a manner that each one power supply pad is interposed between each pair of signal input/output pads and a number of unitary pad arrays each of which consists of a signal pad, a power supply pad and another signal pad located in the named order are repeatedly arranged along a peripheral edge of the chip. Thus, the pad pitch can be reduced to two thirds of the width of an I/O cell, without changing the I/O cell size. In addition, since the power supply pad is located adjacent each of the I/O cells, it is effective to suppress or minimize the power supply voltage noise caused by the simultaneous driving.

FIGURE 1A



15

20

25

30

35

45

50

55

Background of th Invention

Field of the invention

The present invention relates to a master slice integrated circuit, and more specifically to an improved location of connection pads and input/output cells in the master slice integrated circuit.

1

Description of related art

Master slice integrated circuits have been constructed so that a number of circuit elements such as transistors, which constitute a number of logic circuits called "internal cells", are located in the form of a matrix at a center zone of an integrated circuit chip, and a number of circuit elements, which constitute a number of input/output circuits called "I/O cells" for interfacing between the internal cells and external circuits, are arranged to surround the zone of the internal cells. A number of connection pads are located at constant intervals at a periphery of the integrated circuit chip for interconnection between the I/O cells and lead terminals of a package. In general, a width of each of the I/O cells is made equal to a pitch of the pads.

In addition, a pair of power supply wiring conductors are located to pass over all the "I/O cells", so as to form two closed loops which surround the internal cell zone. The power supply wiring conductors are connected to the pads used for the power supply.

With recent improved performance of systems using the gate arrays, further increase of the integration density and the operation speed has become required. Because of the increase of the operation speed, the power consumption has increased, and the amount of electric current flowing through the power supply wiring conductors correspondingly increases. Accordingly, a voltage drop caused at a location remote from the power supply pad because of a wiring resistance of the power supply wiring conductors has become not negligible, and therefore, it has become necessary to increase the number of power supply pads provided on a single chip. This is more remarkable in the case that ECL logic circuits are formed.

In conventional integrated circuits, the power supply wiring conductors are connected to corresponding power supply pads through conductors which extending from the power supply pads to the power supply wiring conductors. As a result, a region of the I/O c II zon adjacent to ach of the power supply pads cannot be us d as an element formation region since there is no signal pad, and therefore, no circuit lem nts ar formed in the region in question, so that the region in question is

I ft as a wasteful empty region.

With the increased number of conn ction pins or t rminals and th incr ased operation sp ed, wh n a plurality of connection terminals are simultaneously driven from a low level to a high level or vice versa, a large amount of electric current flows into or out from a ground level wiring conductor. Under this circumstance, in a terminal near to the terminal whose condition has changed from the low level to the high level or vice versa, the logic voltage level exceeds a threshold (which is a boundary level between the high level and the low level) for an instant, with the result that a malfunction occurs. Namely, this simultaneous driving gives a large adverse influence. As a countermeasure for this simultaneous driving, it is necessary to strenathen the power supply wiring conductors, and it has been known to locate the power supply pads adjacent to the terminals which are simultaneously driven. Because of this, an increased number of power supply pads have become necessary. In addition, an increased number of signal pads have also become required because of the increase of the integration density. These result in an increased size of chip.

On the other hand, in order to save the cost, it is necessary to make the chip size small. However, the miniaturization of the chip size is subjected to many restrictions such as a restriction attributable to an assembling operation including a wire bonding operation and a restriction due to the size of the I/O cells. In a recent technology, in the case of using a TAB (Tape Automated Bonding) process, the pitch of pads can be shortened to 80 µm, but it rather becomes difficult to reduce the size of the I/O cells, because various functions have been required for the input/output circuits and because the current flowing through the I/O cells have become large. As a result, since the pitch of the pads is the same as the width of the I/O cells as mentioned hereinbefore, the size of the chip is determined by the width of the I/O cells.

Summary of the Invention

Accordingly, it is an object of the present invention to provide a master slice integrated circuit which has overcome the above mentioned defect of the conventional one.

Another object of the present invention is to provide a master slice integrated circuit having the increased of power supply pads but a reduced chip size, and capable of minimize the power supply voltage noise caused by the simultaneous driving.

Th above and other objects of th pr sent invention are achiev d in accordance with the pr s nt invention by a master slice integrated circuit including an internal cell zone which is defined

10

15

20

30

35

40

45

50

55

at a center area of an integrated circuit chip and in which a number of internal cells are located in the form of a matrix, an input/output c II zon d fined on the int grated circuit chip so as to surround the internal cell zone, the input/output cell zone including therein a number of input/output cells located in a single array along a side of the integrated circuit chip, a number of signal pads and a number of power supply pads located at an outside of the input/output cell zone and along a peripheral edge region of the integrated circuit chip, each of the input/output cells being connected to a corresponding one of the signal pads, and at least one power supply wiring conductor located to pass over all the input/output cells and therefore to surround the internal cell zone, the at least one power supply wiring conductor being connected to the power supply pads, the signal pads and the power supply pads being arranged in such a manner that each one power supply pad is interposed between each pair of adjacent signal input/output pads and a number of unitary pad arrays each of which consists of a signal pad, a power supply pad and another signal pad located in the named order are repeatedly arranged along a peripheral edge of the integrated circuit chip.

The above and other objects, features and advantages of the present invention will be apparent from the following description of preferred embodiments of the invention with reference to the accompanying drawings.

Brief Description of the Drawings

Figure 1A is a partial layout pattern diagram of a first embodiment of the master slice integrated circuit in accordance with the present invention; Figure 1B is an enlarged layout pattern diagram of a portion of the I/O cell zone in the master slice integrated circuit shown in Figure 1A; and Figure 2 is an enlarged partial layout pattern diagram of a portion of the I/O cell zone in a second embodiment of the master slice integrated circuit in accordance with the present invention.

Description of the Preferred embodiments

Referring to Figure 1, there is shown a partial layout pattern diagram of a first embodiment of the master slice integrated circuit in accordance with the present invention. An enlarged layout pattern diagram of a portion of the I/O cell zone in the shown mast r slic integrated circuit is shown in Figur 1B.

The first embodiment of the master slice integrated circuit in accordance with the present invention includes an internal cell zone 2 which is

defined at a center ar a of an integrated circuit chip 10 of a rectangular shap and in which a numb r of int rnal c lls 1 ar locat d in th form of a matrix. An I/O c II zon 4 ar d fined so as to surround the internal cell zone 2, and in the I/O cell zone 4, a number of I/O cells 3 are located to form a single array extending along each side of the rectangular chip 10. In addition, a number of signal pads 51 and a number of power supply pads 52 are located at an outside of the I/O cell zone 4 so as to form a single array extending along a peripheral edge region of the chip 10. Pads including the signal pads 51 and the power supply pads 52 are arranged at the same pitch. Each of the I/O cells 3 is connected to a corresponding one of the signal pads 51. A pair of power supply wiring conductors 6A and 6B are located to pass over all the I/O cells 3 and therefore to surround the internal cell zone 2. For example, one of the power supply wiring conductors 6A and 6B is for a positive or negative voltage, and the other is for a ground level.

In the shown embodiment, the signal pads 51 and the power supply pads 52 are located in such a manner that each two signal pads 51 are located at each side of each power supply pads 52, namely, each two signal pads 51 and one power supply pad 52 are alternately located along a peripheral edge of the chip 10. In other words, a number of unitary pad arrays, each of which consists of one signal pad 51, one power supply pad 52 and another signal pad 51 located in the named order, are repeatedly arranged along a peripheral edge of the chip 10. In addition, the power supply pads 52 themselves are alternately connected to the power supply wiring conductors 6A and 6B through drawout conductors 12 each extending from one power supply pad 52 to a corresponding one of power supply wiring conductors 6A and 6B along a boundary line between a pair of adjacent I/O cells 3 as shown in detail in Figure 1B. Therefore, if oddnumbered power supply pads 52 are connected to the power supply wiring conductor 6A, even-numbered power supply pads 52 are connected to the power supply wiring conductor 6B.

In the above mentioned arrangement, since one power supply pad 52 and the draw-out conductor 12 connected thereto are located at either side of each I/O cell 3, it is possible to suppress or minimize the adverse influence of the simultaneous driving. The reason for this is that the driving current flowing through the I/O cell can be efficiently supply or drawn through the power supply pad 52 by an external power supply, and therefore, it is possible to minimiz th voltag drop which would otherwise occur in th pow r supply wiring conductors.

In addition, as will b und rstood from Figur 1B, the width P_2 of ach I/O c II can be made one

10

15

20

25

30

35

40

45

50

55

(.)

and a half tim s of th pitch P_1 of th pads 51 and 52. Therefor, the I/O c lls can have a wider width.

In th cas of a master slic integrat d circuit designed for th TAB ass mbling, th pad pitch and the I/O cell width are designed to be on the order of 80µm in order to reduce the chip size. In assembling such a chip into a package, the pad pitch has to be expanded to 100µm because of a limit attributable to the wire bonding. In this case, the internal cell zone is not modified, but the I/O cell zone must be modified or newly designed. According to the present invention, when the pad pitch is 100µm, the I/O cell width can be made to 150µm. In this case, since the I/O cell width can be xpanded, the length of the I/O cell can correspondingly be reduced, with the result that the chip siz can be also reduced.

Alternatively, as shown in Figure 2 which shows an enlarged partial layout pattern diagram of a portion of the I/O cell zone in a second embodiment of the master slice integrated circuit in accordance with the present invention, the 150µm width of the I/O cell can be divided to a first area having a width of 80 m in which circuit elements for an input/output circuit for the TAB are located, and a second area having a width of 70µm in which circuit elements for a level conversion circuit, a boundary scan circuit, a test circuit, or the like are located. Therefore, a pair of adjacent input/output cells 3 shown in Figure 2 are constructed in such a manner that the circuit blocks 7 and 8 included in one of the pair of adjacent input/output cells are located in symmetry to the circuit blocks 8 and 7 included in the other of said pair of adjacent input/output cells. Accordingly, it is a matter of course that it is possible to construct the pair of adjacent input/output cells 3 in such a manner that all circuit elements included in one of the pair of adjacent input/output cells are located in symmetry to all circuit elements included in the other of said pair of adjacent input/output cells.

With this arrangement, a multi-function of I/O c IIs can be advanced.

As will be apparent from the above, according to the present invention, each one power supply pad is interposed between each pair of signal input/output pads, and a number of unitary pad arrays, each of which consists of a signal pad, a-power supply pad and another signal pad located in the named order, are repeatedly arranged along a peripheral edge of the chip. Thus, the pad pitch can be reduced to two thirds of the pad pitch of the conventional integrated circuit, without changing the I/O c II siz. In addition, since the power supply pad is located adjacent each of the I/O cells, it is ffective to suppress or minimize the power supply voltage noise caused by the simultan ous driving.

The invention has thus been shown and described with reference to the specific embodiments. However, it should be noted that the present invention is in no way limited to the details of the illustrated structures but changes and modifications may be made within the scope of the appended claims.

Claims

1. A master slice integrated circuit including:

an internal cell zone which is defined at a center area of an integrated circuit chip and in which a number of internal cells are located in the form of a matrix;

an input/output cell zone defined on said integrated circuit chip so as to surround said internal cell zone, said input/output cell zone including therein a number of input/output cells located in a single array along a side of said integrated circuit chip;

a number of signal pads and a number of power supply pads located at an outside of said input/output cell zone and along a peripheral edge region of said integrated circuit chip, each of said input/output cells being connected to a corresponding one of said signal pads; and

at least one power supply wiring conductor located to pass over all said input/output cells and therefore to surround said internal cell zone, said at least one power supply wiring conductor being connected to said power supply pads,

said signal pads and said power supply pads being arranged in such a manner that each one power supply pad is interposed between each pair of adjacent signal input/output pads and a number of unitary pad arrays each of which consists of a signal pad, a power supply pad and another signal pad located in the named order are repeatedly arranged along a peripheral edge of said integrated circuit chip.

- A master slice integrated circuit claimed in Claim 1 wherein pads including said signal pads and said power supply pads are arranged at the same pitch.
- A master slice integrated circuit claimed in Claim 1 wherein said the pitch of pads including said signal pads and said power supply pads is two thirds of the width of said input/output cells.
- A master slic integrat d circuit claimed in Claim 1 wherein said at least one power sup-

ply wiring conductor is connected to said powr supply pads through draw-out conductors ach xt nding from on power supply pad to said power supply wiring conductor along a boundary line between a pair of adjacent input/output cells.

5. A master slice integrated circuit claimed in Claim 1 wherein a pair of power supply wiring conductors are located to pass over all said input/output cells and therefore to surround said internal cell zone, and wherein said power supply pads are alternately connected to said pair of power supply wiring conductors through draw-out conductors each extending from one power supply pad to a corresponding one of said pair of power supply wiring conductors along a boundary line between a pair of adjacent input/output cells.

6. A master slice integrated circuit claimed in Claim 1 wherein at least a pair of adjacent input/output cells are constructed in such a manner that circuit blocks included in one of said pair of adjacent input/output cells are located in symmetry to circuit blocks included in the other of said pair of adjacent input/output cells. 10

15

20

25

30

35

40

45

50

55

FIGURE 1A

a , 41 ° °

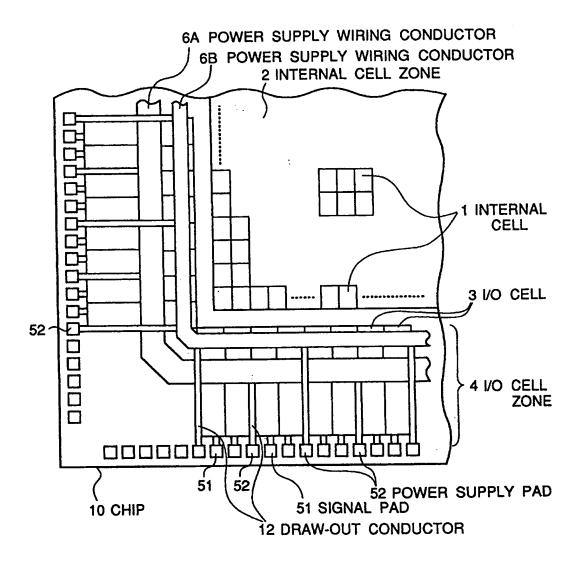


FIGURE 1B

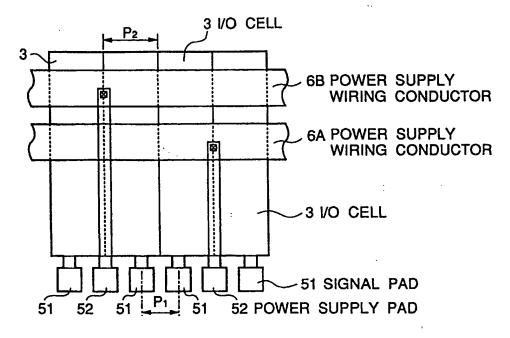


FIGURE 2

